

Rol

COMPLIANT

HALOGEN

FREE

Vishay Siliconix

Low Voltage, Dual DPDT in miniQFN16

DESCRIPTION

The DG2599 is a C_{MOS} Dual DPDT (Dual Double Pole Double Throw) analog switch that operates over a wide voltage range of 1.65 V to 5 V. It is optimized for portable applications switching audio, SIM card signals, and other low power signals.

The DG2599 features low ON resistance of 2.8 Ω at 3 V power supply, fast switching speed, and low power consumption even when control logic signals are below V+ power supply voltage. The well matched dual DPDT switches conduct signals equally in both directions. The DG2599 is designed to guarantee break before make switching.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2599 are offered in a miniQFN package. The miniQFN package has a nickel palladium- gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

DG2599DN-T1-GE4

NC2 GND NO3 COM3 Top View

FEATURES

- Halogen-free according to IEC 61249-2-21 definition
- Low voltage operation 1.65 V to 5 V
- Low on-resistance 2.8 Ω at V+ = 3 V
- Power off protection on COM1 and COM2 pins
- Latch up current great than 300 mA per JESD78
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Cellular phones
- PMPs and PDAs
- Modems and peripherals
- Computers and ebooks
- Tablet devices
- Displays and gaming
- STB

ORDERING INFORMATION Part Number

COM1 NO1 V+ NC4			
	TRUTH TABLE (
	Logic	N	
	0		

NO4

NC3

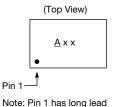
IN3, IN4

TRUTH TABLE (DG2599)			
Logic	NC1, 2, 3 and 4	NO 1, 2, 3 and 4	
0	ON	OFF	
1	OFF	ON	

Package

miniQFN16 1.8 mm x 2.6 mm





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IN1, IN2

NO2

COM2

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Parameter		Symbol	Limit	Unit	
Deference to CND	V+		- 0.3 to 5	V	
Reference to GND	IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)	- V	
Current (any terminal except NO, NC or COM)			30		
Continuous Current (NO, NC, or COM)			± 300	mA	
Peak Current (pulsed at 1 ms, 10 % duty cycle)			± 500		
Storage Temperature (D Suffix)			- 65 to 150	℃	
Package Solder Reflow Conditions ^d	older Reflow Conditions ^d miniQFN16		250		
Power Dissipation (Packages) ^b miniQFN16 ^c			525	mW	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board.

c. Derate 6.6 mW/°C above 70 °C.

d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

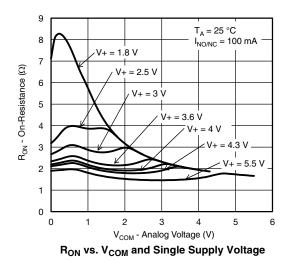
Parameter	Test Conditions	Temp.	Min.	Тур.	Max.	Unit	
Power Supply and Signal				•			
V+ Supply Voltage		Full	1.65		5	V	
V+ Supply Current	V _{IN} = 0 or V+	Full		0.001	2	μA	
Analog Signal Range		Full	0		V+	V	
Switch On-Resistance and Leakage	9						
Drain-Source On-Resistance	1/1 = 2/1 = -100 = 0.01/2.21/1	Room		2.8	3.3		
	V+ = 3 V, $I_{NO/NC}$ = 100 mA, V_{COM} = 0.9 V, 2.3 V	Full			3.6	Ω	
On-Resistance Flatness	1/1 = 2/1 = -100 m (1/1 = -0.10)/1	Room		0.24	1.1	- 52	
On-Resistance Flatness	$V_{+} = 3 V, I_{NO/NC} = 100 mA, V_{COM} = 0 to V_{+}$	Full			1.3	1	
Switch Off Lookage Current		Room	- 10	0.1	10		
Switch Off Leakage Current	$V + = 4.3 V$, $V_{NO/NC} = 0.3 V/4 V$, $V_{COM} = 4 V / 0.3 V$	Full	- 100		100	- 	
Channel On Leakage Current	$V_{1} = 42V_{1}V_{2}$ and $V_{2} = 0.2V_{1}/4V_{2}$	Room	- 10	0.1	10	nA	
Channel On-Leakage Current	V+ = 4.3 V, V _{NO/NC} and V _{COM} = 0.3 V / 4 V	Full	- 100		100	1	
Digital Control	·				•		
Input, High Voltage	V+ = 4.3 V	Full	1.6			v	
	V+ = 3 V		1.3				
land Land Mallana	V+ = 4.3 V	Full			0.6		
Input, Low Voltage	V+ = 3 V				0.5		
Input, Bias Current	V _{IN} = V+	Full	- 1	0.01	1	μA	
Dynamic Characteristics	·			•	•		
Turn On-Time	V_{COM} or $V_{NO/NC}$ = 3 V, R_{L} = 50 Ω , C_{L} = 35 pF	Room			90		
Ium on-Time	v_{COM} or $v_{NO/NC} = 3 v$, $H_L = 30.22$, $C_L = 35 \text{ pF}$	Full			115	1	
Turn Off-Time		Room			70	- 	
Turn Off-Time	V_{COM} or $V_{NO/NC}$ = 3 V, R_L = 50 Ω, C_L = 35 pF	Full			85	ns	
Break Before Make Time	$V_{1} = 2V_{1} = -5000 = -25 \text{ pc}$	Room	2			1	
break belore wake Time	V_{COM} or $V_{NO/NC}$ = 3 V, R_L = 50 Ω , C_L = 35 pF	Full	2			1	
Charge Injection	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega$	Room		± 10		pC	
Off Isolation	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz			- 66			
Crosstalk	$R_L = 50 \Omega$, $C_L = 5 pF$, f = 1 MHz Non-adjacent channels			- 110		dE	
3dB Bandwith	$C_L = 5 \text{ pF}, R_L = 50 \Omega$			186		MH	
Source Off Capacitance	V _{IN} = 0 or V+, f = 1 MHz			9			
Channel On Capacitance	$V_{IN} = 0 \text{ or } V_{+}, f = 1 \text{ MHz}$			26		pF	

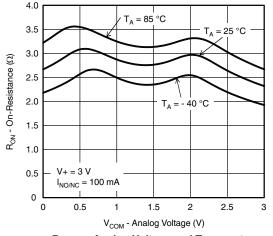
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)





R_{ON} vs. Analog Voltage and Temperature

20

Temperature (°C)

Supply Current vs. Temperature

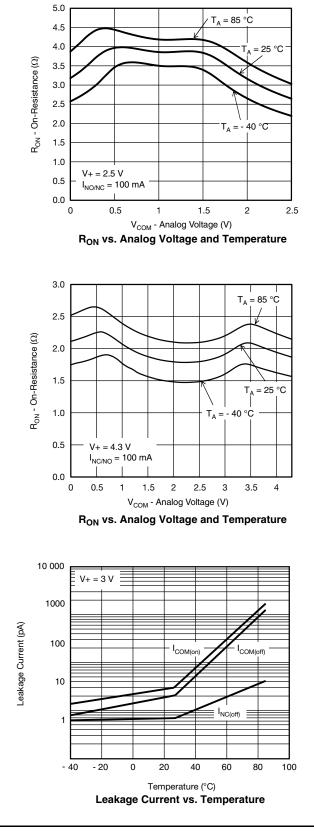
0

40

60

80

100



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100

10

1

0.1

0.01

0.001

- 60

- 40

- 20

I+ - Supply Current (nA)

V+ = 3 V

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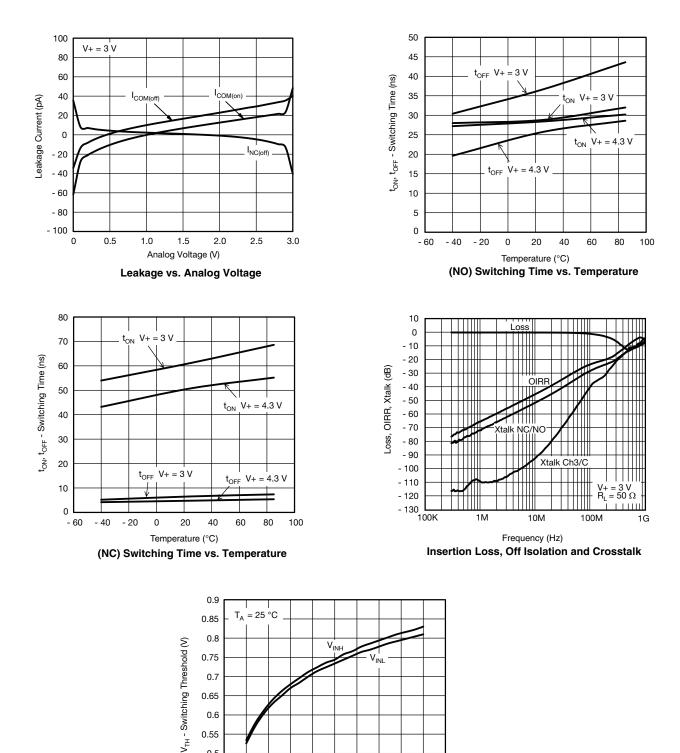


TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

0.55 0.5 0.45 0.4

1.5 2 2.5 3 3.5 4 4.5 5 5.5 6

1



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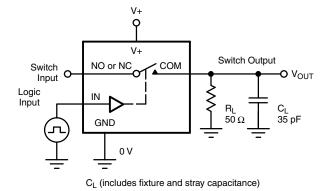
V+ - Supply Voltage (V) Switching Threshold vs. Supply Voltage



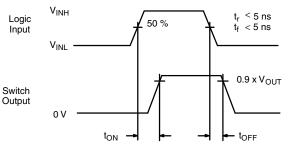
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TEST CIRCUITS



 $V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

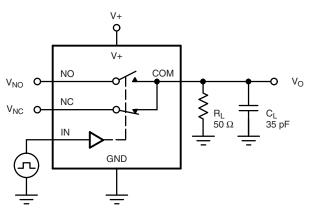
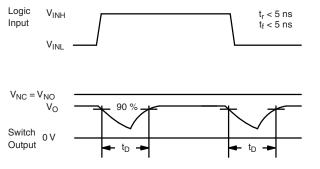
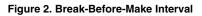


Figure 1. Switching Time



C_L (includes fixture and stray capacitance)



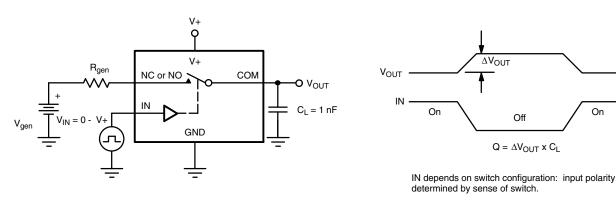


Figure 3. Charge Injection

On

DG2599

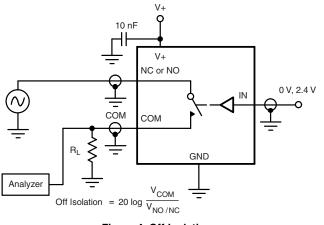
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TEST CIRCUITS





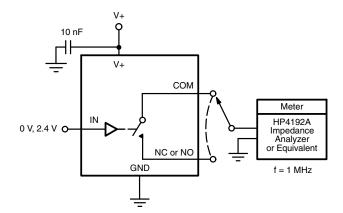


Figure 5. Channel Off/On Capacitance

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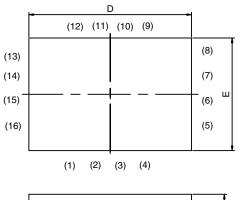
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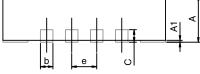
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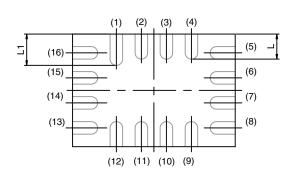


Package Information Vishay Siliconix

MINI QFN-16L







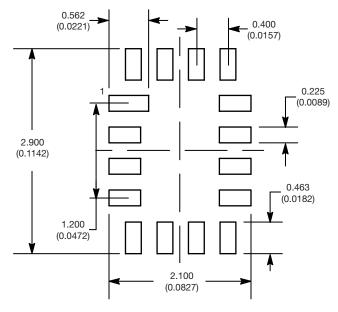
BACK SIDE VIEW

DIM	Μ	MILLIMETERS			INCHES		
DIW	MIN.	NAM	MAX.	MIN.	NAM	MAX.	
Α	0.70	0.75	0.80	0.0275	0.0295	0.0315	
A1	0	-	0.05	0	-	0.002	
b	0.15	0.20	0.25	0.0059	0.0078	0.0098	
С	0.15	0.20	0.25	0.0059	0.0078	0.0098	
D	2.60 BSC				0.1023 BSC	;	
Е	1.80 BSC			0.0708 BSC			
е	0.40 BSC				0.0157 BSC	;	
L	0.35	0.40	0.45	0.0137	0.0157	0.0177	
L1	0.45	0.50	0.55	0.0177	0.0196	0.0216	

ECN T-06380-Rev. A, 14-Aug-06	
DWG: 5954	



RECOMMENDED MINIMUM PADS FOR MINI QFN 16L



Mounting Footprint Dimensions in mm (inch)



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